MBR30H90PT, MBR30H100PT

Vishay General Semiconductor

Dual Common Cathode High Voltage Schottky Rectifier

High Barrier Technology for Improved High Temperature Performance



PRIMARY CHARACTERISTICS					
I _{F(AV)}	2 x 15 A				
V _{RRM} 90 V, 100 V					
I _{FSM}	265 A				
V _F	0.67 V				
I _R	5.0 μΑ				
T _J max.	175 °C				
Package	TO-3P (TO-247AD)				
Circuit configuration	Common cathode				

FEATURES

- Power pack
- Guardring for overvoltage protection
- Lower power losses, high efficiency
- · Low forward voltage drop
- Low leakage current
- High forward surge capability
- High frequency operation
- Solder dip 275 °C max., 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

TYPICAL APPLICATIONS

For use in low voltage, high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters, or polarity protection application.

MECHANICAL DATA

Case: TO-3P (TO-247AD)

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T _A = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	MBR30H90PT	MBR30H100PT	UNIT	
Maximum repetitive peak reverse voltage		V_{RRM}	90	100	V	
Working peak reverse voltage	Working peak reverse voltage		90	100	V	
Maximum DC blocking voltage		V_{DC}	90	100	V	
Maximum average forward rectified current	total device	1	30		А	
	per diode	I _{F(AV)}	15			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I _{FSM}	265		А	
Peak repetitive reverse surge current at t_p = 2 μ s, 1 kHz per diode		I _{RRM}	1.0		Α	
Non-repetitve avalanche energy (I _{AS} = 0.5 A, L = 60 mH) per diode		E _{AS}	7.5		mJ	
Voltage rate of change (rated V _R)		dV/dt	10 000		V/µs	
Operating junction and storage temperature range		T _J , T _{STG}	-65 to +175		°C	

Revision: 27-May-2020 1 Document Number: 88678

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ELECTRICAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MBR30H90PT	MBR30H100PT	UNIT
Maximum instantaneous forward voltage per diode	V _F (1)	I _F = 15 A	T _J = 25 °C	0.82		V
		I _F = 15 A	T _J = 125 °C	0.67		
		$I_F = 30 \text{ A}$	T _J = 25 °C	0.	93	V
		I _F = 30 A	T _J = 125 °C	0.)	
Maximum instantaneous reverse current at rated DC blocking voltage per diode	I _R ⁽¹⁾		T _J = 25 °C	5	.0	μΑ
			T _J = 125 °C	6	.0	mA

Note

 $^{^{(1)}\,}$ Pulse test: 300 μs pulse width, 1 % duty cycle

THERMAL CHARACTERISTICS (T _A = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	L MBR30H90PT MBR30H100PT		UNIT	
Thermal resistance, junction to case per diode	$R_{ heta JC}$	1.6		°C/W	

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-247AD	MBR30H100PT-E3/4W	6.13	45	30/tube	Tube		

RATINGS AND CHARACTERISTICS CURVES (T_A = 25 °C unless otherwise noted)

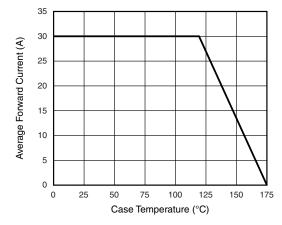


Fig. 1 - Forward Derating Curve

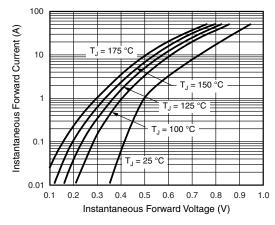


Fig. 2 - Typical Instantaneous Forward Characteristics Per Diode



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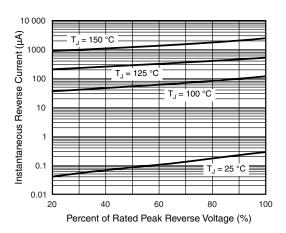


Fig. 3 - Typical Reverse Characteristics Per Diode

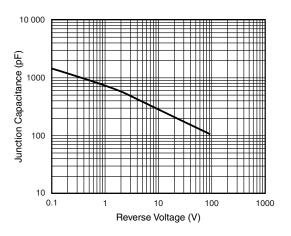
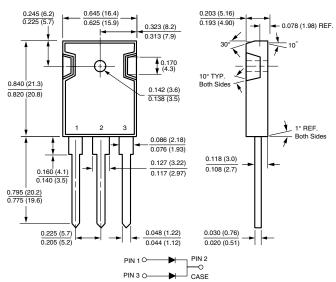


Fig. 4 - Typical Junction Capacitance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-3P (TO-247AD)



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